**Journal of Interdisciplinary Mathematics** ISSN: 0972-0502 (Print), ISSN: 2169-012X (Online) Vol. 23 (2020), No. 2, pp. 617–629 DOI : 10.1080/09720502.2020.1731967



# Chaotic step length artificial bee colony algorithms for protein structure prediction

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# Thermal Science and Engineering Progress



## Performance evaluation of diesel-additives ternary fuel blends: An experimental investigation, numerical simulation using hybrid Entropy-TOPSIS method and economic analysis



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Keywords Diesel Diethyl ether Emissions Engine performance Fuel economy MCDM Entropy TOPSIS

ARTICLE INFO

#### ABSTRACT

Research in the field of alternative, clean and renewable bio-fuels has increased dramatically in recent years for performance improvement, emission control and running cost reduction in internal combustion engines due to continuously increasing prices of conventional fuels, depletion of fossil fuels and environmental protection. In this work, a direct injection VCR diesel engine was used in experimental investigations for determining the combustion characteristics of D-NM-DEE blends at different compression ratios. By exhaust emission and performance analysis of the diesel engine at peak load and standard compression ratio (18.5), D-NM2.5-DEE7.5 (nitromethane 2.5%, diethyl ether 7.5% and diesel 90%) blend was identified as the best fuel blend among all fuel blends and pure diesel. Furthermore, all the considered fuels with different CR at peak load were ranked by the Entropy-TOPSIS method. From the analysis, D-NM2.5-DEE7.5 at CR-19.5 (ranked first with RCi-0.922231) was found as the best fuel blend among all fuel blends and different compression ratios considered with similar experimental conditions. By the comparison of the best fuel blend (D-NM2.5-DEE7.5 at CR 19.5) with pure diesel (at standard CR 18.5), a significant improvement in engine performance, and reduction in emission and fuel cost was achieved.

#### 1. Introduction

For many decades, continuous research is being carried out in the area of alternative clean fuels and expected to be continued due to several reasons such as increasing cost and depletion of conventional fossil fuels day by day, growing energy demand, greater air pollution and other serious environment related problems rising due to excessive burning of fossil fuels [1-3]. Fossil fuel meets about 80% of the total energy demand, out of which 50% is being used in the internal combustion (IC) engines for transportation [4,5].

Diesel is the mostly used fossil fuel, which mainly contains aliphatic hydrocarbons and its combustion in a diesel engine is responsible for various types of emissions (i.e., carbon monoxide (CO), hydrocarbon (HC), carbon dioxide (CO2), smoke, particulate matter (PM), nitrogen oxide (NOx), etc.). In order to control these emissions, it is very important to enhance the combustion characteristic of compression ignition (CI) engine  $\lfloor 6-8 \rfloor$ . It can be possible by engine modification which is relatively tricky and expensive due to sophisticated design [9], or by using biodiesel which may improve the engine performance and reduce

https://doi.org/10.1016/j.tsep.2020.100675

emissions, however NOx increases [10-14]. Therefore, the use of clean alternative biofuel additives with diesel has supported the substantial research in modern era to enhance engine efficiency (i.e. brake thermal efficiency (BTE) and brake specific fuel combustion (BSFC)) and reduce exhaust emissions by improving the combustion characteristics of fuel [15-17]

Very good combustion and chemical characteristics (i.e., oxygen content, cetane number (CN), low boiling point, latent heat, miscible characteristics, etc.) of nitromethane (NM) and diethyl ether (DEE) make them suitable additives for blending with diesel [18-21]. Table 1 exhibits the comparative presentation of important combustion and physico-chemical properties of diesel, nitromethane and diethyl ether. Important outcomes of research studies conducted by past researchers using nitromethane and diethyl ether with diesel are exhibited in Tables 2 and 3 respectively.

Nowadays, various multi-criteria decision-making (MCDM) techniques (i.e., Technique for order preference by similarity to ideal solution (TOPSIS), Vlse kriterijumska optimizacija kompromisno resenje (VIKOR), Elimination et choix traduisant la realite (ELECTRE), Analytic

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Received 16 March 2020; Received in revised form 21 July 2020; Accepted 31 July 2020 2451-9049/ © 2020 Elsevier Ltd. All rights reserved.



Materials Today Proceedings 30 (2020) 217-220

Contents lists available at ScienceDirect



Materials Today: Proceedings

journal homepage: www.elsevier.com/locate/matpr

# Resistive switching characteristics of HfO<sub>2</sub> based bipolar nonvolatile

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## ARTICLE INFO

Article history: Received 19 March 2020 Received in revised form 6 June 2020 Accepted 11 June 2020 Available online 17 July 2020

Keywords: RRAM Switching characteristics HfO<sub>2</sub> Conduction mechanism

#### ABSTRACT

Non-volatile memory (NVM) will play a significant role in the progress of the next-generation of electronic products due to the physical limitations of the conventionally used flash memory. In this paper, switching properties of Cu/HfO2/Pt/Si resistive random access memory device were successfully demonstrated. Semiconductor parameter analyzer (model no. B1500A Agilent) was used for the measurement of the resistive switching characteristics of the fabricated device. It has been observed that the device shows the bipolar mode of switching operation. The temperature dependence of electrical conductivity for low resistance state and high resistance state was also measured in the range from 300 K to 450 K. The switching behaviour of the proposed device explained on the basis of conduction filaments formed in HfO<sub>2</sub>

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Selection and Peer-review under responsibility of the scientific committee of the International Conference on Advancement in Nanoelectronics and Communication Technologies.

#### 1. Introduction

The memory which is used for storing data and program is a main component in any computer system. All recognizable computing platforms such as computer, cell phone, digital cameras, portable electronic gadget and large super-computer use storage systems for storing data, either temporarily or permanently as per their requirement [1]. Uses of nonvolatile memory (NVM) are constantly increasing, due to the huge demand of portable and consumer electronic gadgets, such as memory card, USB storage and smart phone, where NVM is used as a main component. Existing charge storage based non-volatile memory technologies like flash memories have now reached to its physical limits [2]. To overcome the limitations of traditional memories and to bring advancement in new technologies like internet of things (IOT) and big data applications, the memories should be dense, power efficient and robust. Hence nano-scale memories which do not work on charge storing magneto-resistive random access memory (MRAM) [3], ferroelectric random access memory (FeRAM) [4], resistive random access memory (RRAM) [5] and phase change

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random access memory (PCRAM) [6] have drawn a significant interest of researchers for future non-volatile memories. RRAM is a potential candidate for future memories due to its modest components, extraordinary compactness, low power, and exceptional scalability [7]. In recent years, the resistive switching properties in different types of metal oxides such as  $HfO_x$  [8],  $TiO_x$  [9],  $TaO_x$ [10], AlO<sub>x</sub> [11], NiO<sub>x</sub> [12] and ZrO<sub>x</sub> [13] etc. have been largely observed and investigated. Among the various materials proposed for RRAM, HfO<sub>x</sub> is potential candidate due to its superior electrical performance and exceptional compatibility with existing CMOS technology [14-15]. The HfO2 based metal-oxide RRAM have been preferred by many researchers due to its fast operational speed, high integration, low power consumption, and high compatibility with advanced complementary metal-oxide semiconductor technologies [16-17].

Basic resistive switching memory cell as shown in Fig. 1, consists of an insulating/resistive material layer sandwiched between two conductive electrodes. Depending on the polarity of voltage the resistive switching behaviour of RRAM is divided as unipolar switching or bipolar switching. In unipolar switching, resistive switching is induced by a voltage of same polarity but a different magnitude (as shown in Fig. 2). On the other hand, in bipolar switching resistive switching is induced by a voltage of opposite

https://doi.org/10.1016/j.matpr.2020.06.209 2214-7853/© 2020 Elsevier Ltd. All rights reserved.

Selection and Peer-review under responsibility of the scientific committee of the International Conference on Advancement in Nanoelectronics and Communication **Technologies** 



- Recent Trends in Environment and Sustainable Development
- Published: 10 November 2020

# Use of 2-methoxyethyl ether and nitromethane as oxygenated additives for performance improvement and emission reduction of CI engine: experimental investigation and numerical simulation

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Environmental Science and Pollution Research 28, 3960–3971 (2021)

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Chandan Kumar and Kunj Bihari Rana: conceptualization, analysis, writing, reviewing, and editing; Priyanka Verma and Meghna Mahar: experimentation and writing; Shyam Sundar Sharma: supervision.